

TÜV MANAGEMENT SERVICE



An ISO/TS 16949, ISO 9001 and ISO 14001 Certified Company

SILICON PLANAR TRANSISTORS



BC393 PNP BC394 NPN

TO-18 Metal Can Package

High Voltage Transistors

ABSOLUTE MAXIMUM RATINGS

DESCRIPTION	SYMBOL	BC393	BC394	UNIT	
Collector Emitter Voltage	V _{CEO}	180	180	V	
Collector Base Voltage	V _{CBO}	180	180	V	
Emitter Base Voltage	V _{EBO}		6		
Collector Current Continuous	I _C		А		
Power Dissipation @ T _a =25°C	P _D		W		
Derate Above 25°C			mW/ ºC		
Power Dissipation @ T _c =25°C	P _D		W		
Derate Above 25°C		8.00			
Operating and Storage Junction Temperature Range	T _j , T _{stg}	- 65 to +200		°C	

THERMAL CHARACTERISTICS

Junction to Ambient in free air	R _{th (j-a)}	440	°C/W
Junction to Case	R _{th (j-c)}	125	°C/W

ELECTRICAL CHARACTERISTICS (T_a=25°C unless specified otherwise)

DESCRIPTION	SYMBOL	TEST CONDITION	MIN	TYP	MAX	UNIT
Collector Emitter Voltage	V_{CEO}	$I_C=10$ mA, $I_{B=}0$	180			V
Collector Base Voltage	V_{CBO}	I _C =100μA, I _E =0	180			V
Emitter Base Voltage	V_{EBO}	$I_{E}=100\mu A, I_{C}=0$	6			V
Collector Cut off Current	I _{CBO}	$V_{CB}=100V, I_{E}=0$			50	nA
Collector Cut off Current	I _{CEO}	$V_{CE}=100V, I_{B}=0, T_{a}=150^{\circ}C$			50	μΑ
DC Current Gain	*h _{FE}	$I_C=10$ mA, $V_{CE}=10$ V	50			
Collector Emitter Saturation Voltage	*V _{CE (sat)}	$I_C=10mA$, $I_B=1mA$			0.3	V
Base Emitter Saturation Voltage	*V _{BE (sat)}	$I_C=10mA$, $I_B=1mA$			0.9	V

^{*}Pulse Test: Pulse width=300ms, Duty cycle = 2%

DYNAMIC CHARACTERISTICS

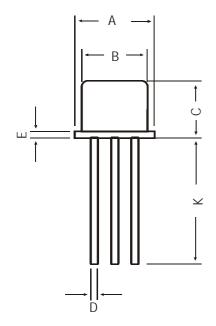
DESCRIPTION	SYMBOL	TEST CONDITION	MIN	TYP	MAX	UNIT
Transition frequency	f _T	I_C =20mA, V_{CE} =20V, f=20MHz	50		200	MHz
Output Capacitance	C _{ob}	V_{CB} =20V, I_E =0, f=1MHz			7	pF
Input Capacitance	C_{ib}	V_{EB} =0.5V, I_{C} =0, f=1MHz		75		рF

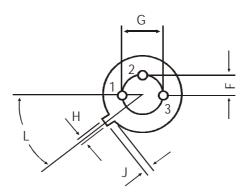
SWITCHING TIMES

DESCRIPTION	SYMBOL TEST CONDITION		MIN	TYP	MAX	UNIT
Turn on Time	t _{on}	I _C =50mA, I _{B1} =10mA, V _{CC} =100V		100		ns
Turn on Time	t _{off}	I _C =50mA, I _{B2} =10mA, V _{CC} =100V		400		ns

TO-18 Metal Can Package

TO-18 Metal Can Package





	DIM	MIN	MAX	
	Α	5.24	5.84	
	В	4.52	4.97	
	С	4.31	5.33	
	D	0.40	0.53	
	Е		0.76	
Ϊ.	F	_	1.27	
=	G		2.97	
SILS	Н	0.91	1.17	
1131	J	0.71	1.21	
All Ullillisions III IIIII.	K	12.70	_	
Ī	L	45 DEG		



PIN CONFIGURATION

- 1. EMITTER
- 2. BASE 3. COLLECTOR

Packing Details

PACKAGE	STANDARD PACK		INNER CARTON BOX		OUTER CARTON BOX		
	Details	Net Weight /Qty	Size	Qty	Size Oty Gr V		Gr Wt
TO-18	1K/polybag	350 gm/1K pcs	3" x 7.5" x 7.5"	5K	17" x 15" x 13.5"	80K	34 kgs

Notes

BC393 PNP BC394 NPN

TO-18
Metal Can Package

Disclaimer

The product information and the selection guides facilitate selection of the CDIL's Discrete Semiconductor Device(s) best suited for application in your product(s) as per your requirement. It is recommended that you completely review our Data Sheet(s) so as to confirm that the Device(s) meet functionality parameters for your application. The information furnished in the Data Sheet and on the CDIL Web Site/CD are believed to be accurate and reliable. CDIL however, does not assume responsibility for inaccuracies or incomplete information. Furthermore, CDIL does not assume liability whatsoever, arising out of the application or use of any CDIL product; neither does it convey any license under its patent rights nor rights of others. These products are not designed for use in life saving/support appliances or systems. CDIL customers selling these products (either as individual Discrete Semiconductor Devices or incorporated in their end products), in any life saving/support appliances or systems or applications do so at their own risk and CDIL will not be responsible for any damages resulting from such sale(s).

CDIL strives for continuous improvement and reserves the right to change the specifications of its products without prior notice.



CDIL is a registered Trademark of
Continental Device India Limited
C-120 Naraina Industrial Area, New Delhi 110 028, India.
Telephone + 91-11-2579 6150 Fax + 91-11-2579 9569, 2579 5290
e-mail sales@cdil.com www.cdil.com www.cdilsemi.com